Serial No.: 09/682,502

Confirmation No.: 7905

Applicant: DANIELSSON, Mats

Atty. Ref.: 06730.0010.NPUS00

**AMENDMENTS TO THE CLAIMS:** 

Please amend the claims as follows:

1-13. (Cancelled)

14. (New) An x-ray imaging arrangement for obtaining diagnostic radiographic images, said

arrangement comprising:

an x-ray emission source located at a spaced-apart distance from an x-ray detector and an

x-ray beam collimator positioned between said x-ray emission source and said x-ray detector;

a silicon substrate based radiation detector comprising a silicon detector wafer having a

mechanically damaged edge zone characterized by the production of interfering background

current during radiation detection;

a plurality of pixel sensor strips being arranged on said silicon detector wafer, each at a

spaced-apart, lateral distance from said mechanically damaged edge zone, said plurality of pixel

sensor strips collectively defining a substantially planar active x-ray detection area of said silicon

detector wafer;

a guard ring being at least partially located laterally between said pixel sensor strips and

said mechanically damaged edge zone and thereby establishing a dead area of said silicon

detector wafer extending interiorly from said guard ring toward said pixel sensor strips; and

said collimator being configured to pass an x-ray beam having a cross-sectional area

measured perpendicular to said x-ray beam smaller than said active x-ray detection area.

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15. (New) The invention as recited in claim 14, wherein said substantially planar active x-ray

detection area is oriented at an angle with respect to said x-ray beam so that no x-rays impinge

upon said dead area.

16. (New) The invention as recited in claim 15, wherein said plurality of pixel sensor strips are

arranged with approximately 25 µm to 100 µm distance between adjacent pixel sensor strips

whereby said x-ray imaging arrangement constitutes a means for producing mammography

diagnostic radiographic images.

17. (New) The invention as recited in claim 15, wherein said thickness of said silicon detector

wafer ranges between approximately 300 µm to 500 µm.

18. (New) The invention as recited in claim 16, wherein said thickness of said silicon detector

wafer is approximately 300 µm and said x-ray emission source emits x-ray energy at

approximately 25keV.

19. (New) The invention as recited in claim 18, wherein said substantially planar active x-ray

detection area is oriented at approximately 87 degrees with respect to said x-ray beam.

20. (New) The invention as recited in claim 16, wherein said detector is connected to an applied

bias voltage of approximately ±80V.

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21. (New) The invention as recited in claim 14, wherein all of said plurality of pixel sensor strips in said detector are arranged at a single, substantially uniform level with respect to said silicon detector wafer without overlap with other pixel sensor strips.

22. (New) The invention as recited in claim 22, wherein said applied bias voltage ranges between approximately 10V and 1000V.